

TOSHIBA Transistor    Silicon NPN Epitaxial Type (PCT process)

# 2SC2459

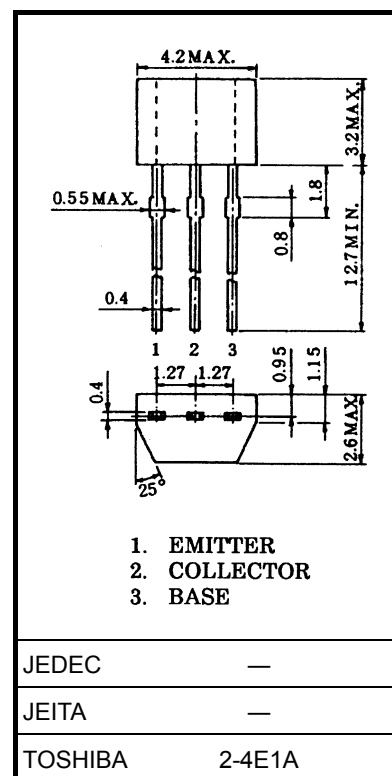
## Audio Amplifier Applications

- High breakdown voltage:  $V_{CEO} = 120\text{ V (max)}$
- High DC current gain:  $h_{FE} = 200\sim 700$
- Excellent  $h_{FE}$  linearity:  $h_{FE}(I_C = 0.1\text{ mA})/h_{FE}(I_C = 2\text{ mA}) = 0.95\text{ (typ.)}$
- Low noise:  $NF = 1\text{ dB (typ.)}$ ,  $10\text{ dB (max)}$
- Complementary to 2SA1049.
- Small package.

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	120	V
Collector-emitter voltage	$V_{CEO}$	120	V
Emitter-base voltage	$V_{EBO}$	5	V
Collector current	$I_C$	100	mA
Base current	$I_B$	20	mA
Collector power dissipation	$P_C$	200	mW
Junction temperature	$T_j$	125	°C
Storage temperature range	$T_{stg}$	-55~125	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

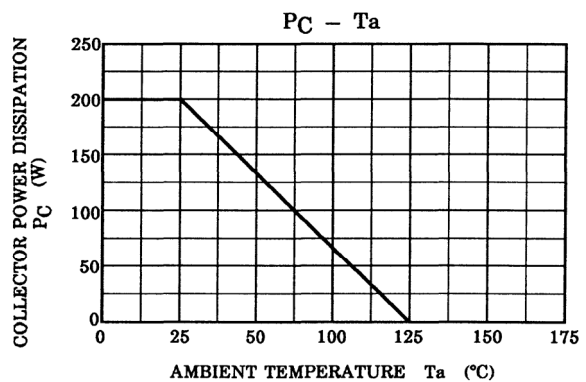
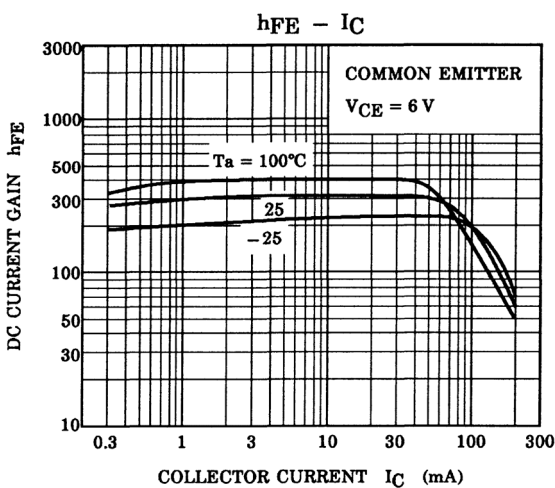
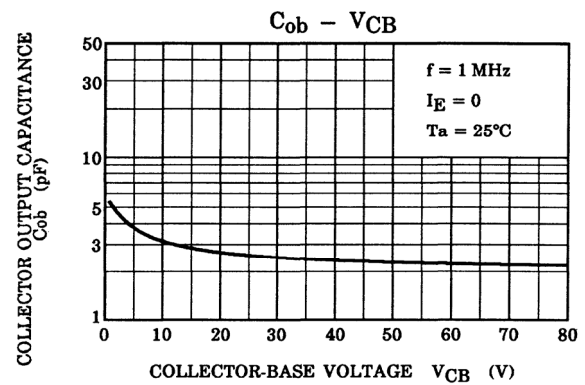
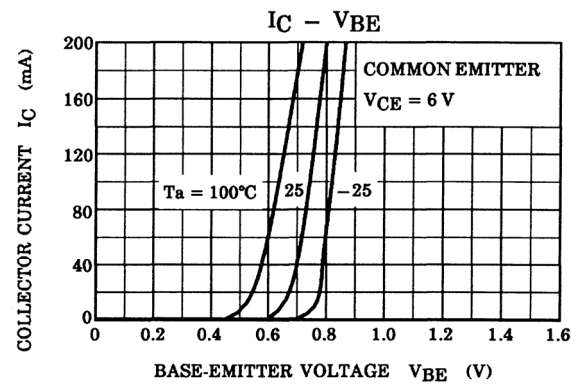
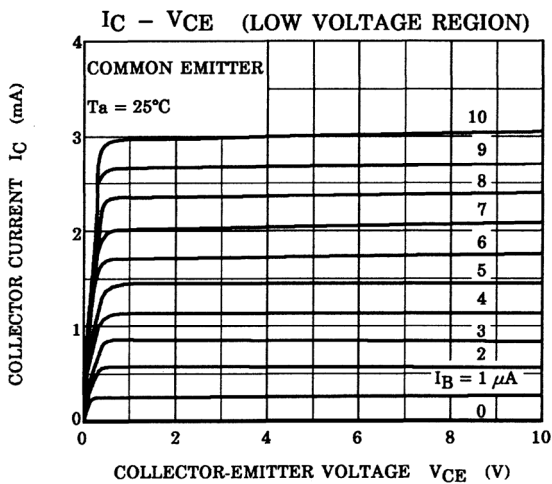
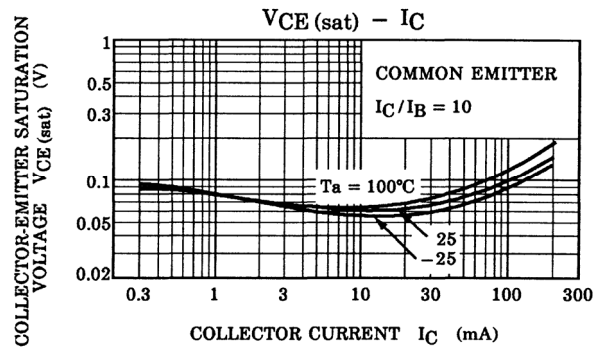
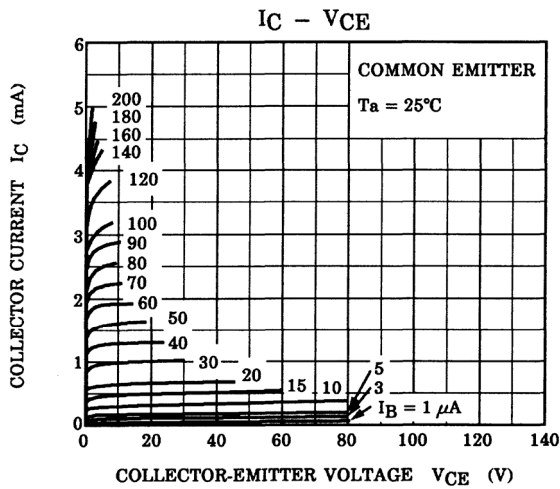


Weight: 0.13 g (typ.)

### Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	$I_{CBO}$	$V_{CB} = 120\text{ V}, I_E = 0$	—	—	0.1	$\mu\text{A}$
Emitter cut-off current	$I_{EBO}$	$V_{EB} = 5\text{ V}, I_C = 0$	—	—	0.1	$\mu\text{A}$
DC current gain	$h_{FE}$ (Note)	$V_{CE} = 6\text{ V}, I_C = 2\text{ mA}$	200	—	700	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C = 10\text{ mA}, I_B = 1\text{ mA}$	—	—	0.3	V
Transition frequency	$f_T$	$V_{CE} = 6\text{ V}, I_C = 1\text{ mA}$	—	100	—	MHz
Collector output capacitance	$C_{ob}$	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	3.0	—	pF
Noise figure	NF	$V_{CE} = 6\text{ V}, I_C = 0.1\text{ mA},$ $f = 1\text{ kHz}, R_G = 10\text{ k}\Omega$	—	1.0	10	dB

Note: hFF classification GR: 200~400, BL: 350~700



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20070701-EN GENERAL

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